NSN 5961-00-439-3731

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View Online at https://aerobasegroup.com/nsn/5961-00-439-3731
Inclosure Material:
Metal
Overall Length:
1.308 inches
End Application:
Kidd class ddg; virginia class cgn (41); 2m/ate microminiauture automatic test equipment; aircraft, (ac-130h, mc-130h, ec-130e, hc-130);
ticonder
Mounting Facility Quantity:
1
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Threaded stud
Overall Width Across Flats:
Between 0.424 inches and 0.437 inches
Thread Size:
0.190 inches
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
800.0 breakover voltage, dc
Current Rating Per Characteristic:
2.00 amperes source cutoff current preset
Power Rating Per Characteristic:
20.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Special Features:
Weapon system essential
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 tab, solder lug and 1 threaded stud
Specification Data:
81349-mil-s-19500/372 government specification

N/a

Shelf Life:

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0